

74LVC1G57-Q100

Low-power configurable multiple function gate

Rev. 2 — 9 December 2016

Product data sheet

1. General description

The 74LVC1G57-Q100 provides configurable multiple functions. Eight patterns of 3-bit input, determine the output state. The user can choose the logic functions AND, OR, NAND, NOR, XNOR, inverter and buffer. All inputs can be connected to V_{CC} or GND.

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of this device in a mixed 3.3 V and 5 V environment.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

All inputs (A, B and C) are Schmitt trigger inputs that can transform slowly changing input signals into sharply defined, jitter-free output signals.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and from $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$
- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant input/output for interfacing with 5 V logic
- High noise immunity
- Complies with JEDEC standard:
 - ◆ JESD8-7 (1.65 V to 1.95 V)
 - ◆ JESD8-5 (2.3 V to 2.7 V)
 - ◆ JESD8B/JESD36 (2.7 V to 3.6 V).
- ESD protection:
 - ◆ MIL-STD-883, method 3015 exceeds 2000 V
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V ($C = 200\text{ pF}$, $R = 0\text{ }\Omega$)
- $\pm 24\text{ mA}$ output drive ($V_{CC} = 3.0\text{ V}$)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options

3. Ordering information

Table 1. Ordering information

| Type number | Package | | | Version |
|------------------|-------------------|-------|--|---------|
| | Temperature range | Name | Description | |
| 74LVC1G57GW-Q100 | -40 °C to +125 °C | SC-88 | plastic surface-mounted package; 6 leads | SOT363 |
| 74LVC1G57GV-Q100 | -40 °C to +125 °C | SC-74 | plastic surface-mounted package; 6 leads | SOT457 |

4. Marking

Table 2. Marking

| Type number | Marking code ^[1] |
|------------------|-----------------------------|
| 74LVC1G57GW-Q100 | YC |
| 74LVC1G57GV-Q100 | V57 |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram

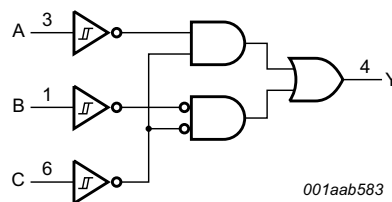


Fig 1. Logic symbol

6. Pinning information

6.1 Pinning

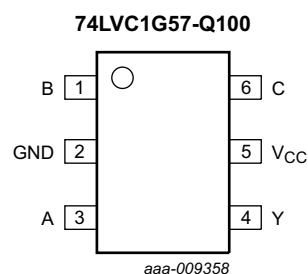


Fig 2. Pin configuration SOT363 and SOT457

6.2 Pin description

Table 3. Pin description

| Symbol | Pin | Description |
|-----------------|-----|----------------|
| B | 1 | data input |
| GND | 2 | ground (0 V) |
| A | 3 | data input |
| Y | 4 | data output |
| V _{CC} | 5 | supply voltage |
| C | 6 | data input |

7. Functional description

Table 4. Function table^[1]

| Input | | | Output |
|-------|---|---|--------|
| C | B | A | Y |
| L | L | L | H |
| L | L | H | L |
| L | H | L | H |
| L | H | H | L |
| H | L | L | L |
| H | L | H | L |
| H | H | L | H |
| H | H | H | H |

[1] H = HIGH voltage level; L = LOW voltage level.

7.1 Logic configurations

Table 5. Function selection table

| Logic function | Figure |
|---------------------------------------|---|
| 2-input AND | see Figure 3 |
| 2-input AND with both inputs inverted | see Figure 6 |
| 2-input NAND with inverted input | see Figure 4 and Figure 5 |
| 2-input OR with inverted input | see Figure 4 and Figure 5 |
| 2-input NOR | see Figure 6 |
| 2-input NOR with both inputs inverted | see Figure 3 |
| 2-input XNOR | see Figure 7 |
| Inverter | see Figure 8 |
| Buffer | see Figure 9 |

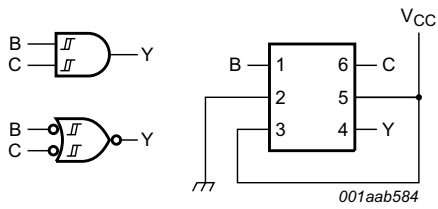


Fig 3. 2-input AND gate or 2-input NOR gate with both inputs inverted

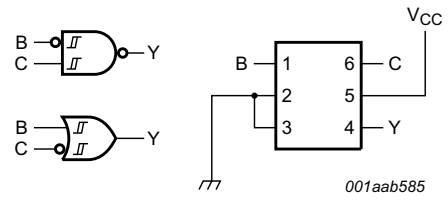


Fig 4. 2-input NAND gate with input B inverted or 2-input OR gate with inverted C input

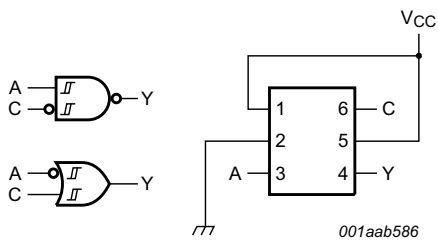


Fig 5. 2-input NAND gate with input C inverted or 2-input OR gate with inverted A input

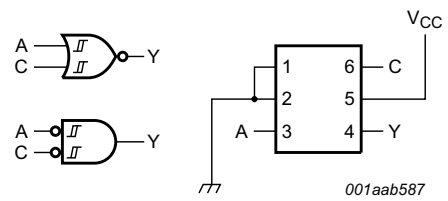


Fig 6. 2-input NOR gate or 2-input AND gate with both inputs inverted

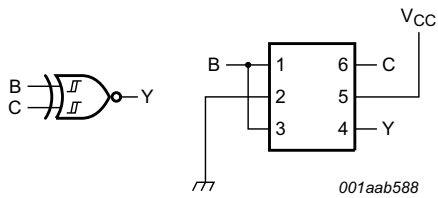


Fig 7. 2-input XNOR gate

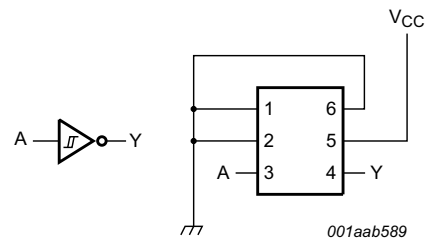


Fig 8. Inverter

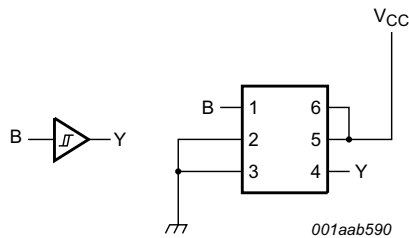


Fig 9. Buffer

8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------|-----------------------------------|------|----------|------|
| V_{CC} | supply voltage | | -0.5 | +6.5 | V |
| I_{IK} | input clamping current | $V_I < 0$ V | -50 | - | mA |
| V_I | input voltage | [1] | -0.5 | +6.5 | V |
| I_{OK} | output clamping current | $V_O > V_{CC}$ or $V_O < 0$ V | - | ± 50 | mA |
| V_O | output voltage | Active mode [1][2] | -0.5 | +6.5 | V |
| | | Power-down mode [1][2] | -0.5 | +6.5 | V |
| I_O | output current | $V_O = 0$ V to V_{CC} | - | ± 50 | mA |
| I_{CC} | supply current | | - | +100 | mA |
| I_{GND} | ground current | | -100 | - | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| P_{tot} | total power dissipation | $T_{amb} = -40$ °C to +125 °C [3] | - | 250 | mW |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] When $V_{CC} = 0$ V (Power-down mode), the output voltage can be 5.5 V in normal operation.

[3] For SC-88 and SC-74 packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.

9. Recommended operating conditions

Table 7. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------|---------------------|---------------------------------|------|-----|----------|------|
| V_{CC} | supply voltage | | 1.65 | - | 5.5 | V |
| V_I | input voltage | | 0 | - | 5.5 | V |
| V_O | output voltage | Active mode | 0 | - | V_{CC} | V |
| | | $V_{CC} = 0$ V; Power-down mode | 0 | - | 5.5 | V |
| T_{amb} | ambient temperature | | -40 | - | +125 | °C |

10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|------------------|---------------------------|--|-----------------------|--------------------|------|-----------------------|------|------|
| | | | Min | Typ ^[1] | Max | Min | Max | |
| V _{OL} | LOW-level output voltage | V _I = V _{T+} or V _{T-} | | | | | | |
| | | I _O = 100 μA; V _{CC} = 1.65 V to 5.5 V | - | - | 0.1 | - | 0.1 | V |
| | | I _O = 4 mA; V _{CC} = 1.65 V | - | - | 0.45 | - | 0.7 | V |
| | | I _O = 8 mA; V _{CC} = 2.3 V | - | - | 0.3 | - | 0.45 | V |
| | | I _O = 12 mA; V _{CC} = 2.7 V | - | - | 0.4 | - | 0.6 | V |
| | | I _O = 24 mA; V _{CC} = 3.0 V | - | - | 0.55 | - | 0.8 | V |
| | | I _O = 32 mA; V _{CC} = 4.5 V | - | - | 0.55 | - | 0.8 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{T+} or V _{T-} | | | | | | |
| | | I _O = -100 μA; V _{CC} = 1.65 V to 5.5 V | V _{CC} - 0.1 | - | - | V _{CC} - 0.1 | - | V |
| | | I _O = -4 mA; V _{CC} = 1.65 V | 1.2 | - | - | 0.95 | - | V |
| | | I _O = -8 mA; V _{CC} = 2.3 V | 1.9 | - | - | 1.7 | - | V |
| | | I _O = -12 mA; V _{CC} = 2.7 V | 2.2 | - | - | 1.9 | - | V |
| | | I _O = -24 mA; V _{CC} = 3.0 V | 2.3 | - | - | 2.0 | - | V |
| | | I _O = -32 mA; V _{CC} = 4.5 V | 3.8 | - | - | 3.4 | - | V |
| I _I | input leakage current | V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V | - | ±0.1 | ±1 | - | ±1 | μA |
| I _{OFF} | power-off leakage current | V _I or V _O = 5.5 V; V _{CC} = 0 V | - | ±0.1 | ±2 | - | ±2 | μA |
| I _{CC} | supply current | V _I = 5.5 V or GND; I _O = 0 A; V _{CC} = 1.65 V to 5.5 V | - | 0.1 | 4 | - | 4 | μA |
| ΔI _{CC} | additional supply current | V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 2.3 V to 5.5 V | - | 5 | 500 | - | 500 | μA |
| C _I | input capacitance | | - | 2.5 | - | - | - | pF |

[1] Typical values are measured at maximum V_{CC} and T_{amb} = 25 °C.

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see [Figure 11](#).

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|-----------------|-------------------------------|---|------------------|--------------------|------|-------------------|------|------|
| | | | Min | Typ ^[1] | Max | Min | Max | |
| t _{pd} | propagation delay | A, B, C to Y; see Figure 10 ^[2] | | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | 1.0 | 6.0 | 14.4 | 1.0 | 18 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 0.5 | 3.5 | 8.3 | 0.5 | 10.4 | ns |
| | | V _{CC} = 2.7 V | 0.5 | 4.2 | 8.5 | 0.5 | 10.6 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 0.5 | 3.8 | 6.3 | 0.5 | 7.9 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 0.5 | 3.0 | 5.1 | 0.5 | 6.4 | ns |
| C _{PD} | power dissipation capacitance | V _{CC} = 3.3 V; V _I = GND to V _{CC} ^[3] | - | 22 | - | - | - | pF |

[1] Typical values are measured at nominal V_{CC} and at T_{amb} = 25 °C.

[2] t_{pd} is the same as t_{PLH} and t_{PHL}

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

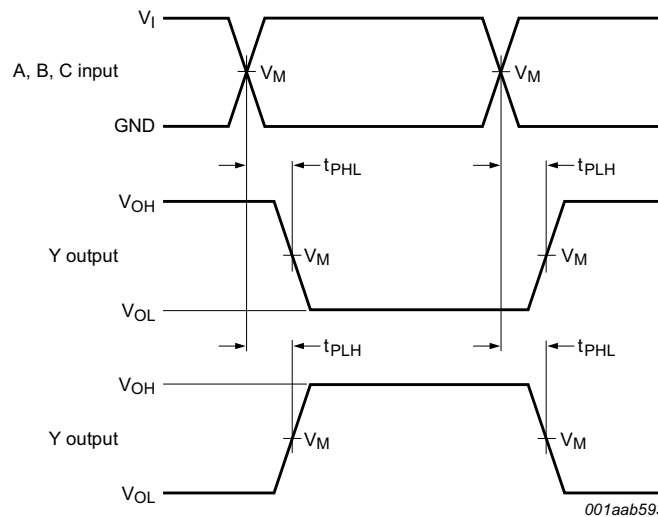
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

Σ(C_L × V_{CC}² × f_o) = sum of outputs.

12. Waveforms



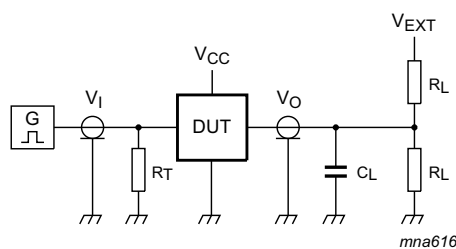
Measurement points are given in [Table 10](#).

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 10. Input A, B and C to output Y propagation delay times

Table 10. Measurement points

| Supply voltage | Input | | Output |
|------------------|-------------|----------|-------------|
| V_{CC} | V_M | V_I | V_M |
| 1.65 V to 1.95 V | $0.5V_{CC}$ | V_{CC} | $0.5V_{CC}$ |
| 2.3 V to 2.7 V | $0.5V_{CC}$ | V_{CC} | $0.5V_{CC}$ |
| 2.7 V | 1.5 V | 2.7 V | 1.5 V |
| 3.0 V to 3.6 V | 1.5 V | 2.7 V | 1.5 V |
| 4.5 V to 5.5 V | $0.5V_{CC}$ | V_{CC} | $0.5V_{CC}$ |



Measurement points are given in [Table 11](#).

Definitions test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig 11. Test circuit for measuring switching times

Table 11. Measurement points

| Supply voltage | Input | | Load | | V_{EXT} |
|------------------|----------|---------------|-------|--------------|--------------------|
| V_{CC} | V_I | $t_r = t_f$ | C_L | R_L | t_{PLH}, t_{PHL} |
| 1.65 V to 1.95 V | V_{CC} | ≤ 2.0 ns | 30 pF | 1 k Ω | open |
| 2.3 V to 2.7 V | V_{CC} | ≤ 2.0 ns | 30 pF | 500 Ω | open |
| 2.7 V | 2.7 V | ≤ 2.5 ns | 50 pF | 500 Ω | open |
| 3.0 V to 3.6 V | 2.7 V | ≤ 2.5 ns | 50 pF | 500 Ω | open |
| 4.5 V to 5.5 V | V_{CC} | ≤ 2.5 ns | 50 pF | 500 Ω | open |

13. Transfer characteristics

Table 12. Transfer characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|-----------------|--|---|------------------|--------------------|------|-------------------|------|------|
| | | | Min | Typ ^[1] | Max | Min | Max | |
| V _{T+} | positive-going threshold voltage | see Figure 12 , Figure 13 , Figure 14 and Figure 15 | | | | | | |
| | | V _{CC} = 1.8 V | 0.70 | 1.02 | 1.20 | 0.67 | 1.20 | V |
| | | V _{CC} = 2.3 V | 1.11 | 1.42 | 1.60 | 1.08 | 1.60 | V |
| | | V _{CC} = 3.0 V | 1.50 | 1.79 | 2.00 | 1.47 | 2.00 | V |
| | | V _{CC} = 4.5 V | 2.16 | 2.52 | 2.74 | 2.13 | 2.74 | V |
| | | V _{CC} = 5.5 V | 2.61 | 2.99 | 3.33 | 2.58 | 3.33 | V |
| V _{T-} | negative-going threshold voltage | see Figure 12 , Figure 13 , Figure 14 and Figure 15 | | | | | | |
| | | V _{CC} = 1.8 V | 0.30 | 0.53 | 0.72 | 0.30 | 0.75 | V |
| | | V _{CC} = 2.3 V | 0.58 | 0.77 | 1.00 | 0.58 | 1.03 | V |
| | | V _{CC} = 3.0 V | 0.80 | 1.04 | 1.30 | 0.80 | 1.33 | V |
| | | V _{CC} = 4.5 V | 1.21 | 1.55 | 1.90 | 1.21 | 1.93 | V |
| | | V _{CC} = 5.5 V | 1.45 | 1.86 | 2.29 | 1.45 | 2.32 | V |
| V _H | hysteresis voltage (V _{T+} - V _{T-}); see Figure 12 , Figure 13 , Figure 14 and Figure 15 | | | | | | | |
| | | V _{CC} = 1.8 V | 0.30 | 0.48 | 0.62 | 0.23 | 0.62 | V |
| | | V _{CC} = 2.3 V | 0.40 | 0.64 | 0.80 | 0.34 | 0.80 | V |
| | | V _{CC} = 3.0 V | 0.50 | 0.75 | 1.00 | 0.44 | 1.00 | V |
| | | V _{CC} = 4.5 V | 0.71 | 0.97 | 1.20 | 0.65 | 1.20 | V |
| | | V _{CC} = 5.5 V | 0.71 | 1.13 | 1.40 | 0.65 | 1.40 | V |

[1] Typical values are measured at T_{amb} = 25 °C.

14. Waveforms transfer characteristics

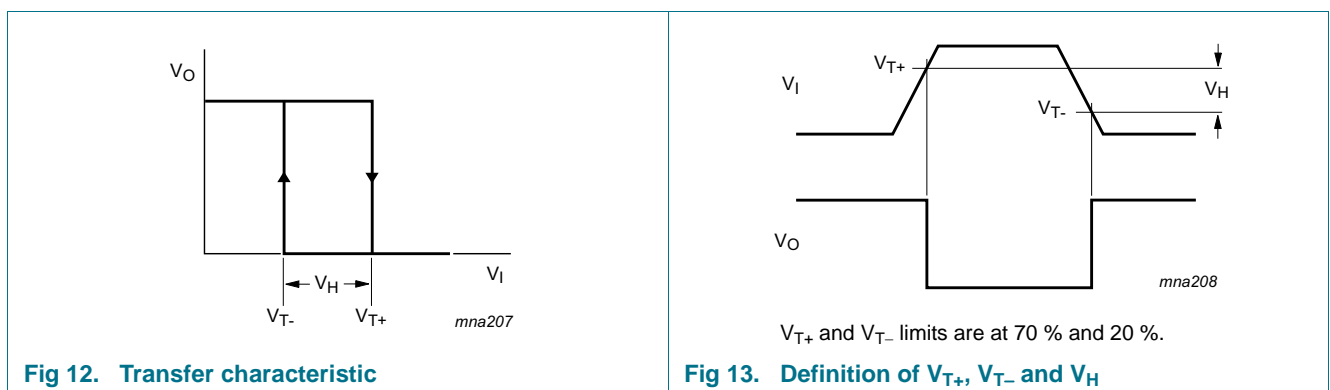


Fig 12. Transfer characteristic

Fig 13. Definition of V_{T+}, V_{T-} and V_H

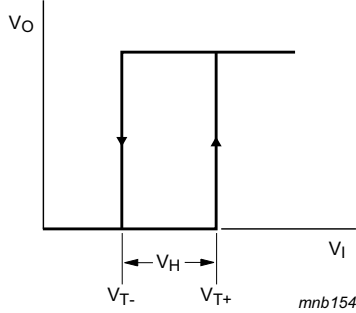
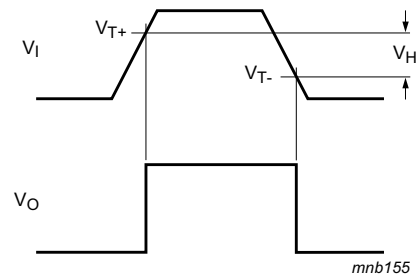


Fig 14. Transfer characteristic



V_{T+} and V_{T-} limits are at 70 % and 20 %.

Fig 15. Definition of V_{T+} , V_{T-} and V_H

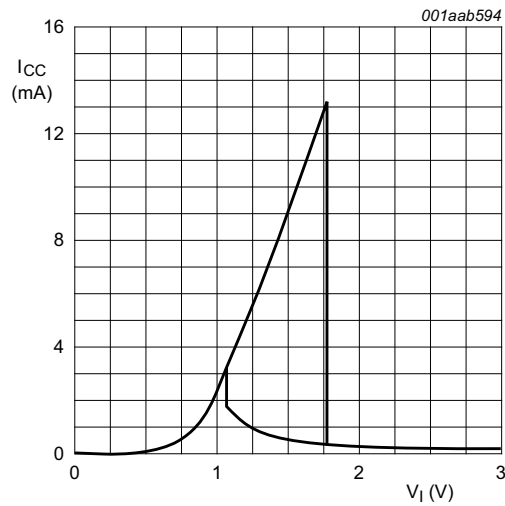


Fig 16. Typical 74LVC1G57-Q100 transfer characteristic; $V_{CC} = 3.0\text{ V}$

15. Package outline

Plastic surface-mounted package; 6 leads

SOT363

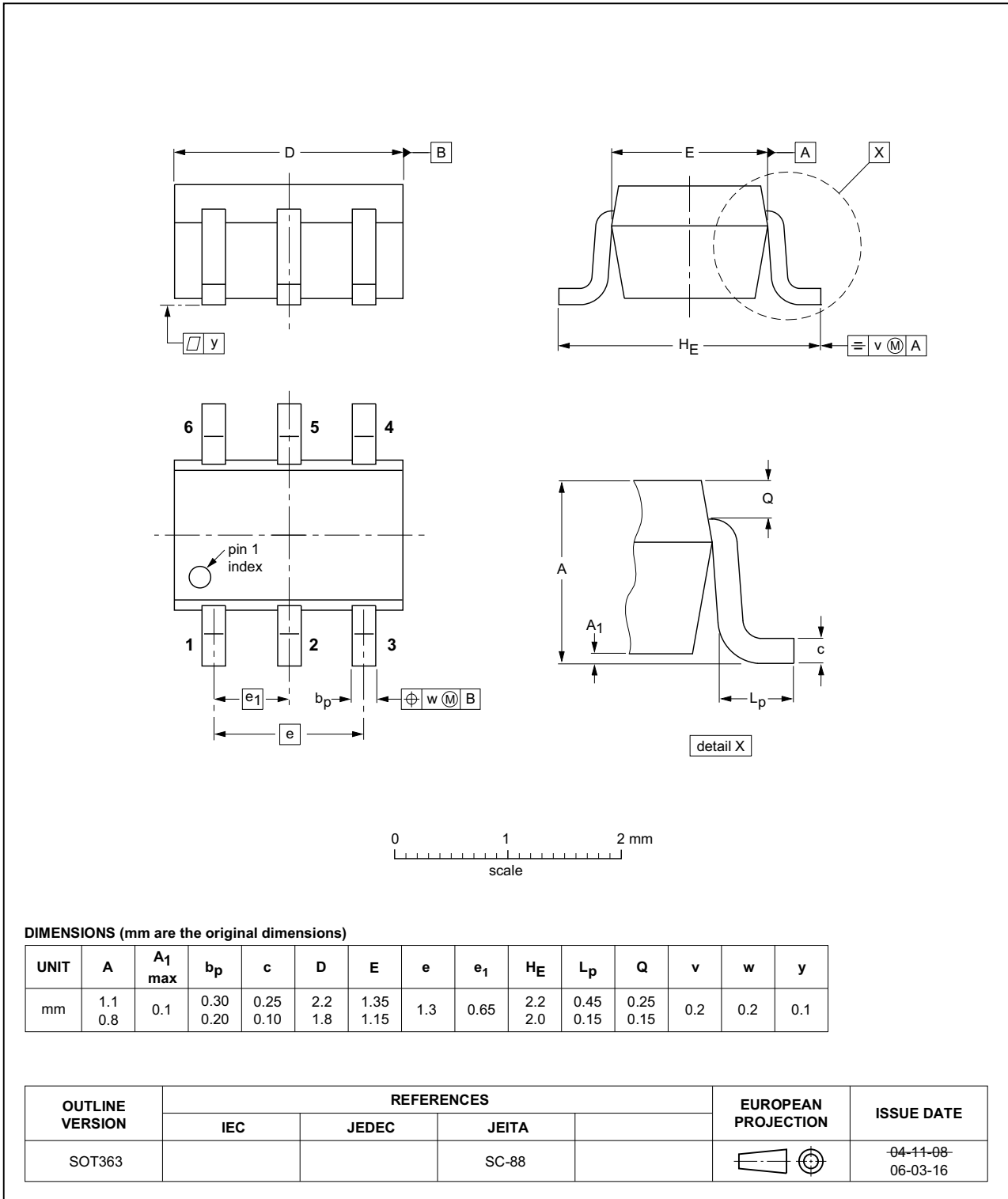


Fig 17. Package outline SOT363 (SC-88)

Plastic surface-mounted package (TSOP6); 6 leads

SOT457

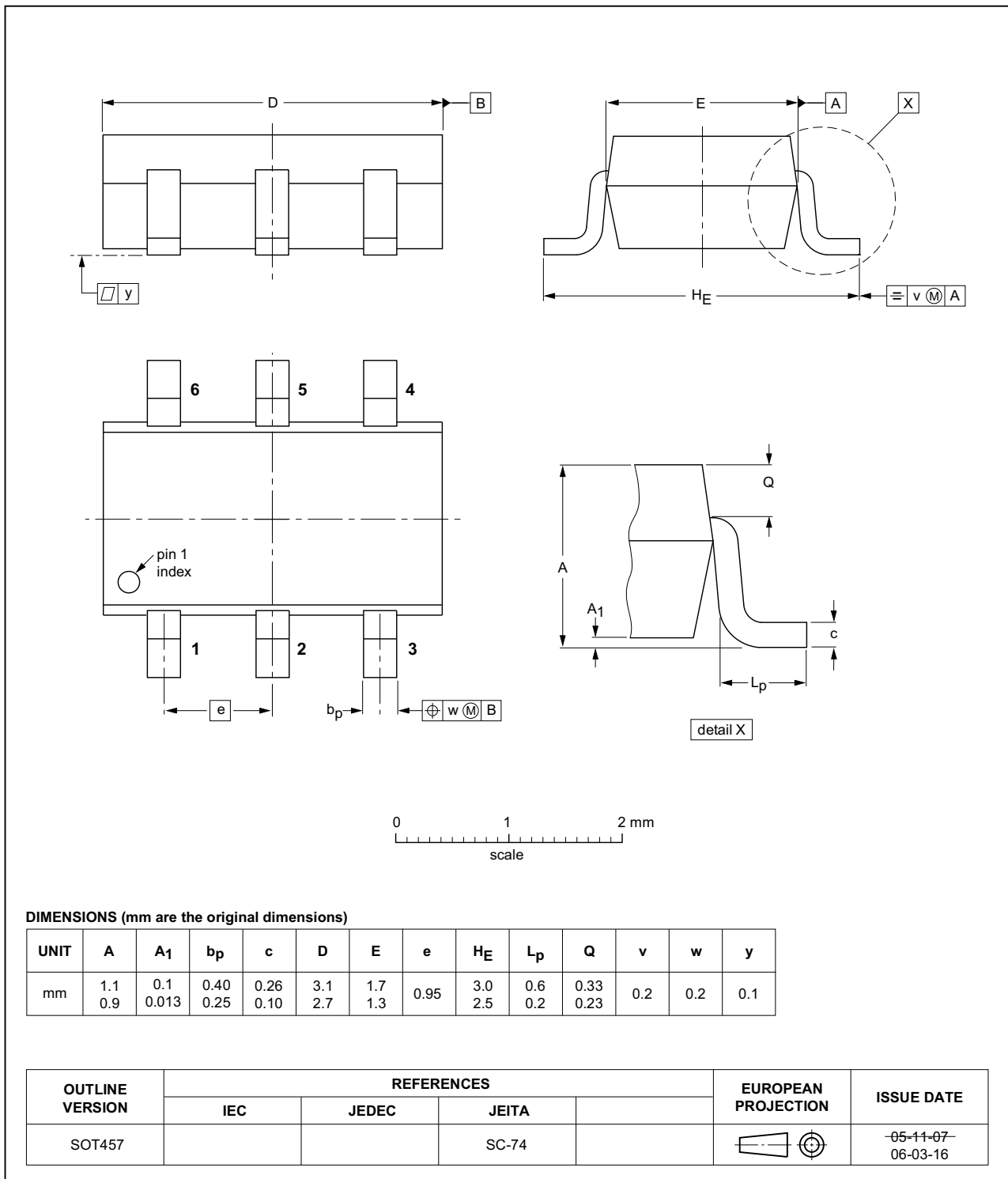


Fig 18. Package outline SOT457 (SC-74)

16. Abbreviations

Table 13. Abbreviations

| Acronym | Description |
|---------|---|
| CMOS | Complementary Metal Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MIL | Military |
| MM | Machine Model |
| TTL | Transistor-Transistor Logic |

17. Revision history

Table 14. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|--------------------|--|--------------------|---------------|--------------------|
| 74LVC1G57_Q100 v.2 | 20161209 | Product data sheet | - | 74LVC1G57_Q100 v.1 |
| Modifications: | <ul style="list-style-type: none"> Table 8: The maximum limits for leakage current and supply current have changed. | | | |
| 74LVC1G57_Q100 v.1 | 20140415 | Product data sheet | - | - |

18. Legal information

18.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nexperia.com>.

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